

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC4408

Power Amplifier Applications

Power Switching Applications

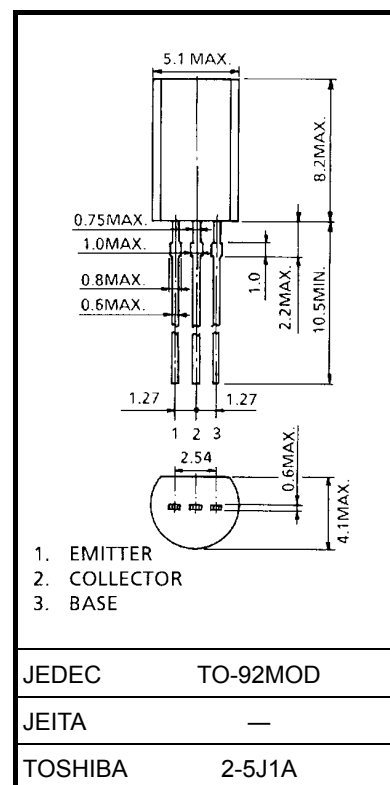
Unit: mm

- Low saturation voltage: $V_{CE(sat)} = 0.5 \text{ V (max)} (I_C = 1 \text{ A})$
- High collector power dissipation: $P_C = 900 \text{ mW}$
- High-speed switching: $t_{stg} = 500 \text{ ns (typ.)}$
- Complementary to 2SA1680

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

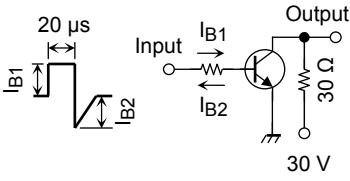
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	80	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_C	2	A
Base current	I_B	0.2	A
Collector power dissipation	P_C	900	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

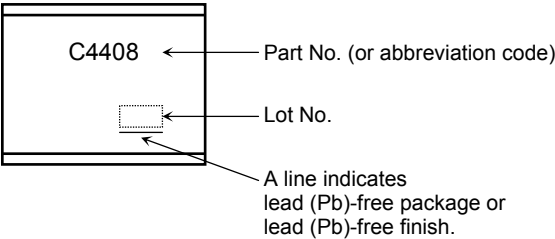


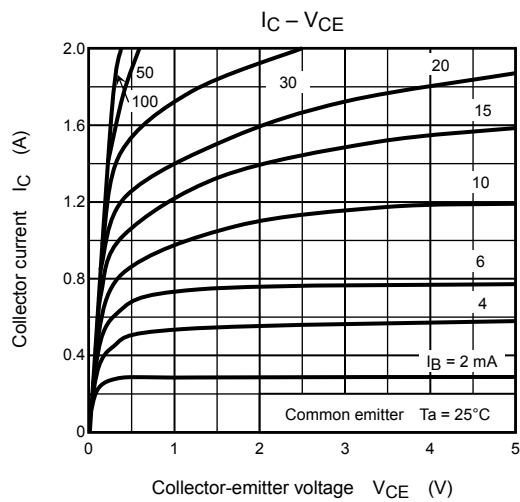
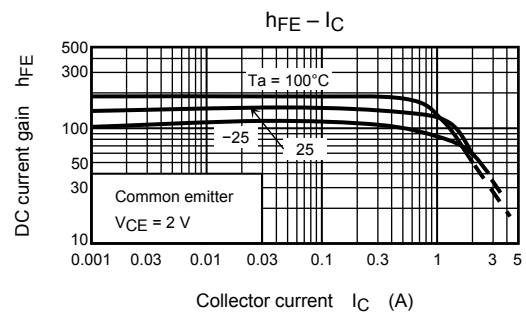
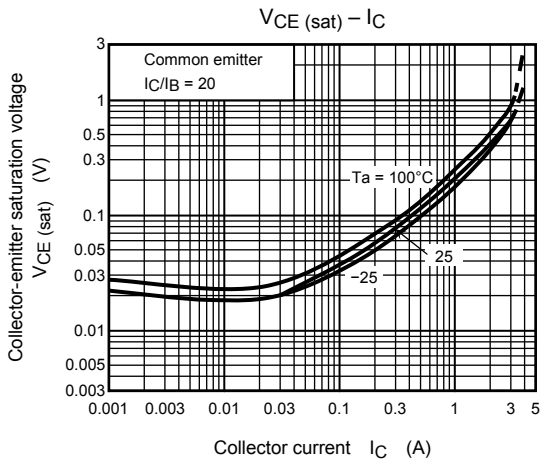
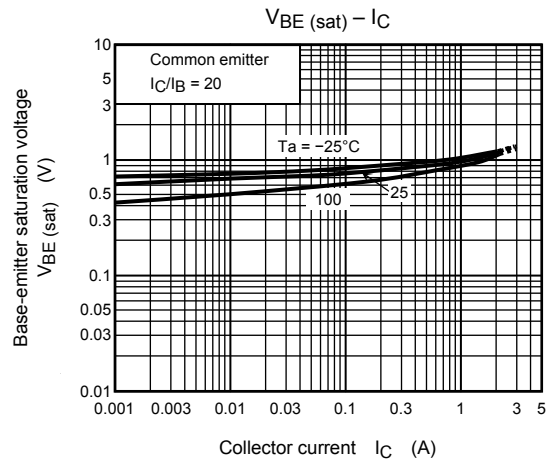
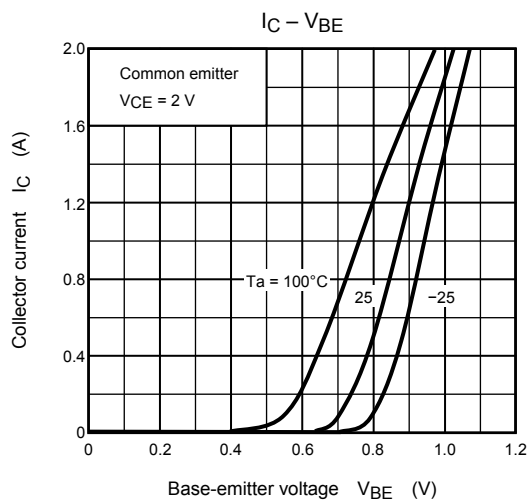
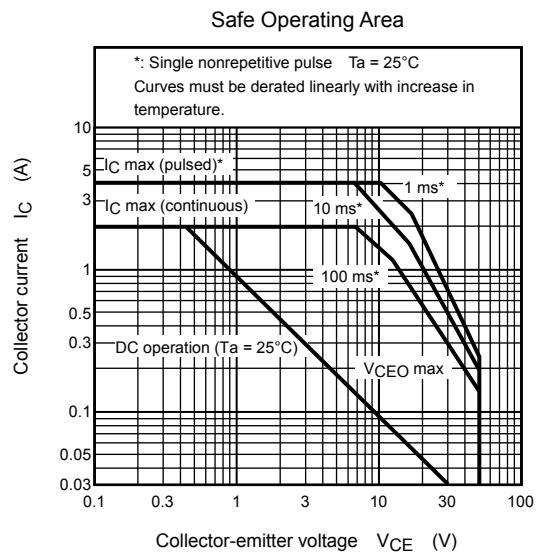
Weight: 0.36 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		ICBO	V _{CB} = 80 V, I _E = 0	—	—	1.0	μA
Emitter cut-off current		IEBO	V _{EB} = 6 V, I _C = 0	—	—	1.0	μA
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	50	—	—	V
DC current gain	h _{FE} (1)		V _{CE} = 2 V, I _C = 100 mA	120	—	400	
	h _{FE} (2)		V _{CE} = 2 V, I _C = 1.5 A	40	—	—	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 1 A, I _B = 0.05 A	—	—	0.5	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 1 A, I _B = 0.05 A	—	—	1.2	V
Transition frequency		f _T	V _{CE} = 2 V, I _C = 100 mA	—	100	—	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _C = 0, f = 1 MHz	—	14	—	pF
Switching time	Turn-on time	t _{on}	 I _{B1} = -I _{B2} = 0.05 A, duty cycle ≤ 1%	—	0.1	—	μs
	Storage time	t _{stg}		—	0.5	—	
	Fall time	t _f		—	0.1	—	

Marking





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